



LD-520-80SG

- Green Laser Diode
- 520 nm, 80 mW
- Single transverse mode
- TO38 package, Flat Window



Description

LD-520-80SG is a direct emitting, **GaN based**, 520 nm green laser diode in 3.8 mm TO-Can. It offers single transverse mode emission and >100 Mhz modulation bandwidth. It is an efficient radiation source for many applications like **laser projection**, holography, metrology, or biomedical application.

Maximum Rating* ($T_{CASE} = 25^{\circ}C$)

Parameter	Symbol	Values		Unit
		Min.	Max.	
Operating Current* ¹	I_{MAX}		300	mA
Reverse Voltage	V_R		2	V
Operating Temperature* ¹	T_{OPR}	- 20	+ 60	°C
Storage Temperature	T_{STG}	- 40	+ 85	°C
Soldering Temperature (max. 3s)	T_{SOL}		+ 260	°C
Junction Temperature* ¹	T_J		+ 120	°C

* operating outside these conditions may damage the device

*¹ operating at maximum ratings may influence the life time



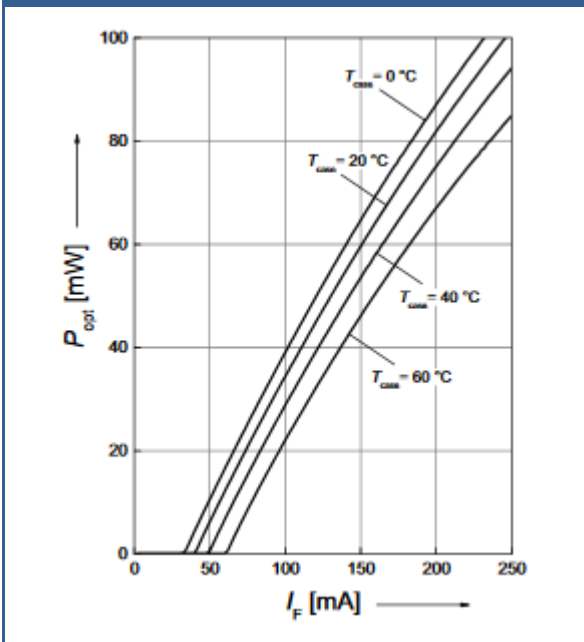
Electro-Optical Characteristics ($T_{CASE} = 25^{\circ}C, P_O = 80mW$)

Parameter	Symbol	Values			Unit	
		Min.	Typ.	Max.		
Peak Wavelength	λ_P	515	520	530	nm	
Spectral Width (FWHM)	$\Delta\lambda$		2		nm	
Operating Voltage	V_F		6.4	8.0	V	
Threshold Current	I_{th}		40	70	mA	
Operating Current	I_F		200	240	mA	
Modulation Frequency	f		>100		MHz	
Polarization	P_{GR}		100:1			
Beam Divergence (FWHM)	parallel	$\Theta_{ }$	5	6.3	7.5	deg.
	perpendicular	Θ_{\perp}	18	22.5	25	deg.
Thermal Resistance (junction to case)	R_{th}		38		K/W	

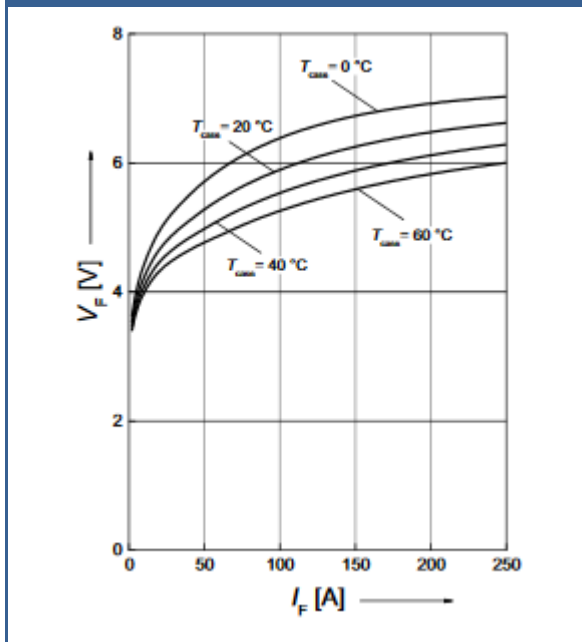


Performance Characteristics

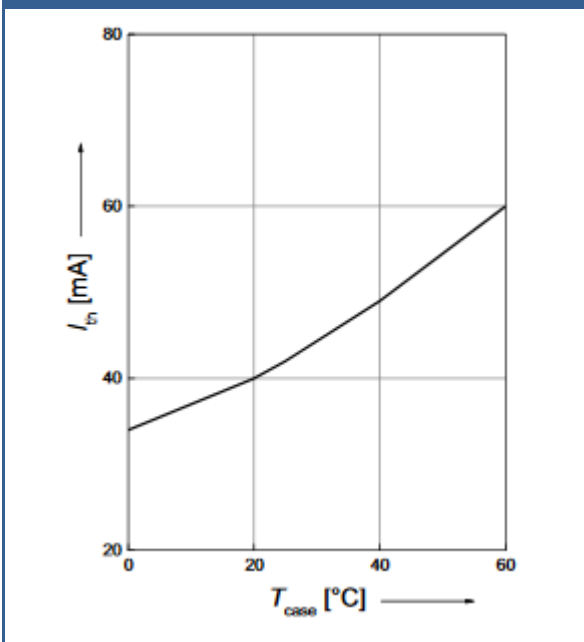
Optical Output Power vs. Operating Current



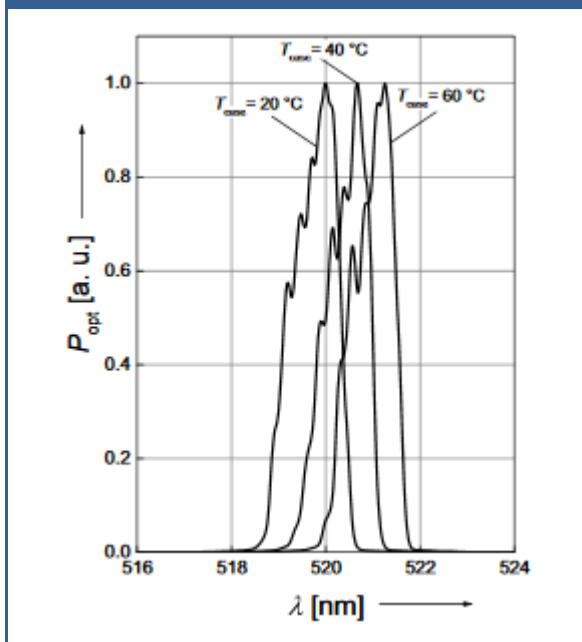
Operating Voltage vs. Operating Current



Threshold Current vs. Temperature

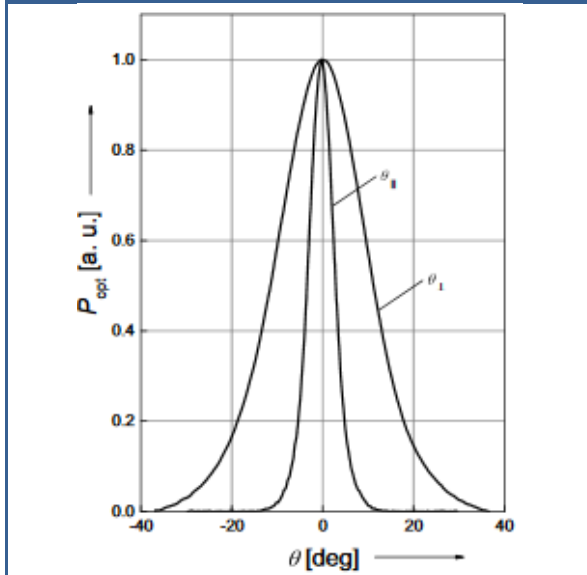


Relative Output Power vs. Wavelength

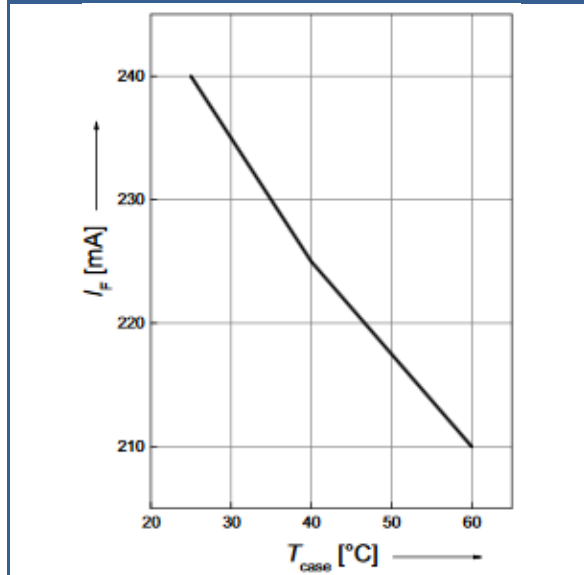




Beam Divergence



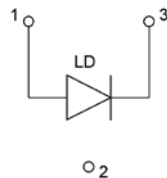
Max. operating Current vs. Temperature



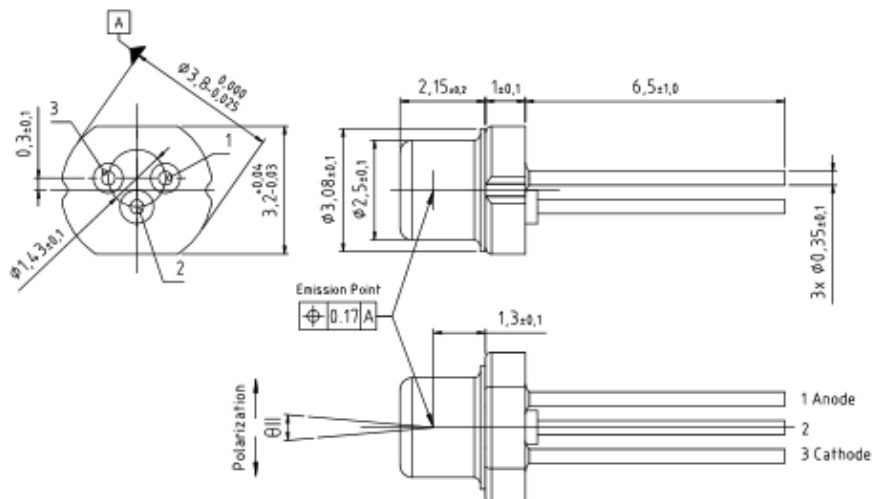
Electrical Connection

Pin Configuration

Pin #	Function
Pin 1	LD Anode
Pin 2	LD Anode, PD Cathode
Pin 3	LD Cathode



Outline Dimensions



All dimensions in mm